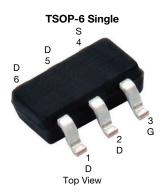


Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.042				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.063				
I _D (A)	7				
Configuration	Single				

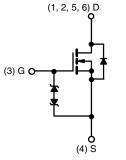
Marking Code: 9IXXX

FEATURES

- TrenchFET® power MOSFET
- Typical ESD protection 800 V HBM
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



ROHS COMPLIANT HALOGEN FREE



N-Channel	

ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free and halogen-free	SQ3426CEEV (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-source voltage		V_{DS}	60	V		
Gate-source voltage	V_{GS}	± 20	V			
Continuous drain current	T _C = 25 °C	1	7			
Continuous drain current	T _C = 125 °C	l _D	4			
Continuous source current (diode conduction)		I _S	4.6	Α		
Pulsed drain current ^a	I _{DM}	29				
Single pulse avalanche current		I _{AS}	10			
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	5	mJ		
Maximum navier dissinction	T _C = 25 °C	D	5	W		
Maximum power dissipation	T _C = 125 °C	P_{D}	1.6	vV		
Operating junction and storage temperature ra	ınge	T _J , T _{stg}	- 55 to +175	°C		

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction-to-ambient P	PCB mount b	R _{thJA}	110	°C/W
Junction-to-foot (drain)			30	G/VV

Notes

- a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$
- b. When mounted on 1" square PCB (FR4 material)



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		60	-	-	V
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$		1.5	2.0	2.5	
Cata agura laglaga		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$		-	-	± 500	nA
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 1	mA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	10	-	-	Α
		V _{GS} = 10 V	I _D = 5 A	-	0.0351	0.042	
Drain acuras an atata registance a	В	V _{GS} = 10 V	I _D = 5 A, T _J = 125 °C	-	0.0627	-	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 5 A, T _J = 175 °C	-	0.0793	-	Ω
		V _{GS} = 4.5 V	I _D = 4 A	-	0.038	0.063	
Forward transconductance a	9 _{fs}	V _{DS}	= 15 V, I _D = 4 A	-	16	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	756	1100	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V, f} = 1 \text{ MHz}$	-	69	100	pF
Reverse transfer capacitance	C_{rss}			-	29	55	
Total gate charge ^c	Q_g			-	13	19.5	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 30 \text{ V}, I_D = 6 \text{ A}$	-	2.6	-	nC
Gate-drain charge ^c	Q_{gd}			1	1.9	1	
Gate resistance	R_g		f = 1 MHz	1.9	3.83	5.7	Ω
Turn-on delay time ^c	t _{d(on)}			-	7	10	
Rise time ^c	t _r		$V_{DD} = 30 \text{ V}, R_{L} = 7.5 \Omega$		4	14	ns
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 4 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		1	18	25	
Fall time ^c	t _f			-	4	6	
Source-Drain Diode Ratings and Character	eristics ^b						
Pulsed current ^a	I _{SM}			1	-	29	Α
Forward voltage	V_{SD}	I _F =	= 1.6 A, V _{GS} = 0	ı	0.76	1.2	V
Body diode reverse recovery time	t _{rr}			1	18	36	ns
Body diode reverse recovery charge	Q _{rr}	I _F = 1.7 A, di/dt = 100 A/μs		ı	14	28	nC
Reverse recovery fall time	ta			ı	14	-	ns
Reverse recovery rise time	t _b			ı	4	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.76	-	Α

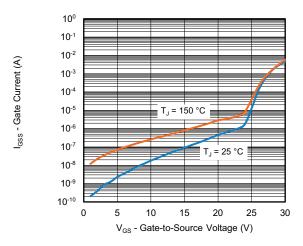
Notes

- a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

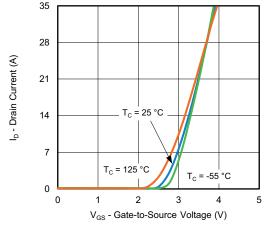
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



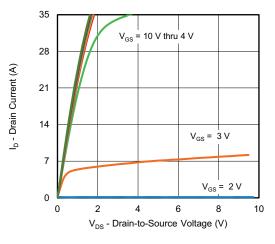
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



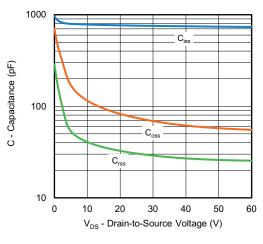
Gate Current vs. Gate-Source Voltage



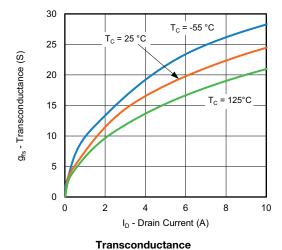
Transfer Characteristics

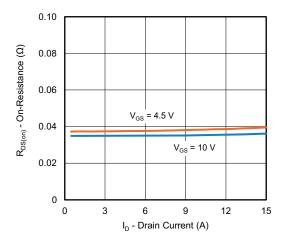


Output Characteristics



Capacitance

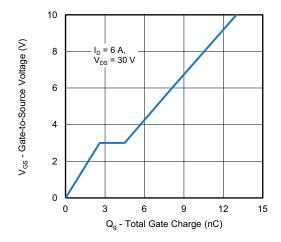




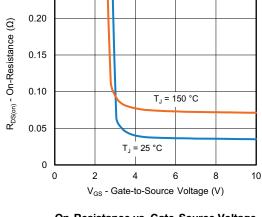
On-Resistance vs. Drain Current



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

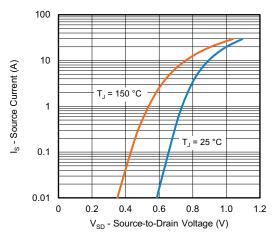


Gate Charge

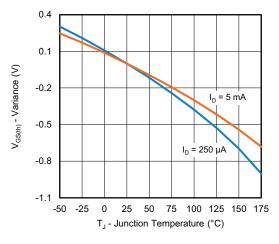


0.25

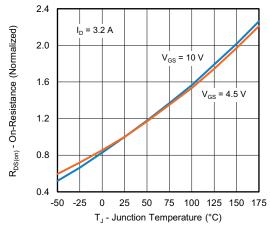
On-Resistance vs. Gate-Source Voltage



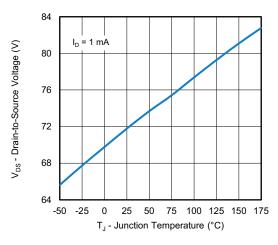
Source-Drain Diode Forward Voltage



Threshold Voltage



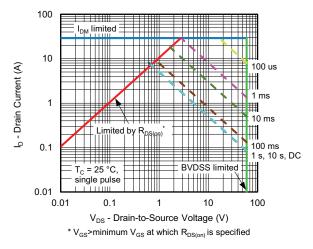
On-Resistance vs. Junction Temperature



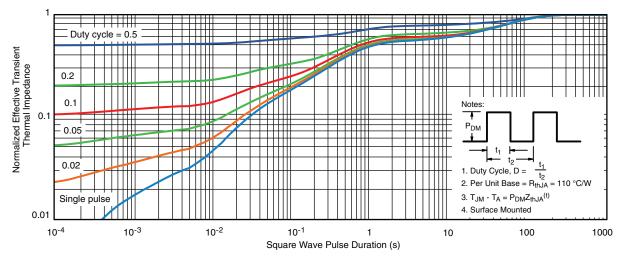
Drain-Source Breakdown vs. Junction Temperature



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



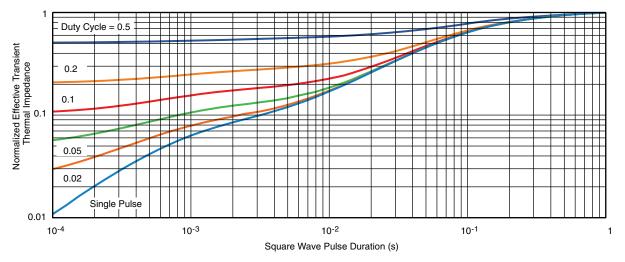
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

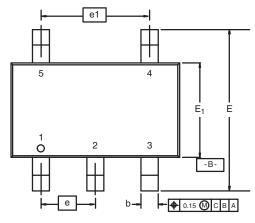
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62147.

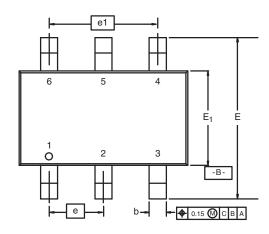




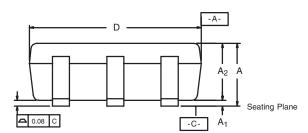
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C

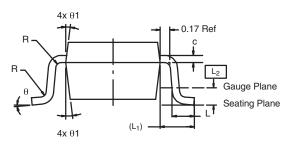




5-LEAD TSOP





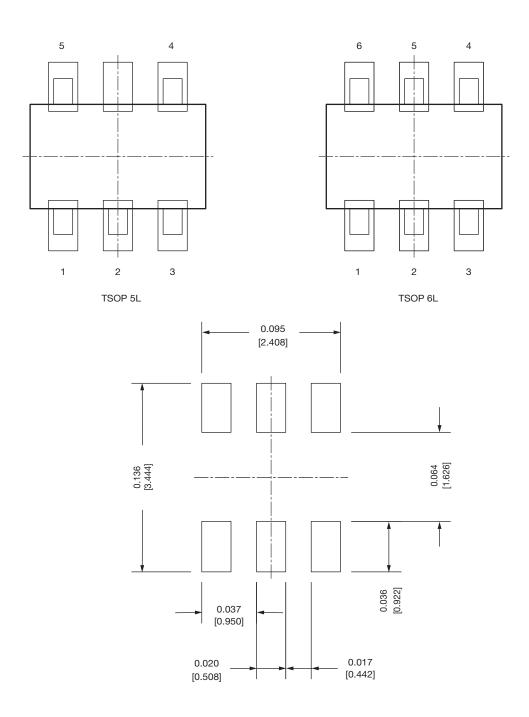


	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116 0.120		0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC			0.0374 BSC		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂		0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ1	7° Nom				7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Document Number: 71200 18-Dec-06



Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010



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